

DATA SHEET

74LVC4066

Quad bilateral switches

Product specification

2003 Aug 12

Quad bilateral switches

74LVC4066

FEATURES

- Very low ON resistance:
 - 7.5 Ω (typical) at $V_{CC} = 2.7$ V
 - 6.5 Ω (typical) at $V_{CC} = 3.3$ V
 - 6 Ω (typical) at $V_{CC} = 5$ V.
- ESD protection:
 - HBM EIA/JESD22-A114-A Exceeds 2000 V
 - MM EIA/JESD22-A115-A Exceeds 200 V.
- High noise immunity
- CMOS low power consumption
- Latch up performance exceeds 250 mA
- Complies with JEDEC standard no. 8-1A
- Direct interface TTL-levels.

DESCRIPTION

The 74LVC4066 is a high-speed Si-gate CMOS device.

The 74LVC4066 has four independent analog switches. Each switch has two input/output terminals (nY and nZ) and an active HIGH enable input (nE). When nE is LOW, the analog switch is turned off.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25$ °C; $t_r = t_f \leq 2.5$ ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PZH}/t_{PZL}	turn-on time E to V_{OS}	$C_L = 50$ pF; $R_L = 500$ Ω ; $V_{CC} = 3$ V	2.5	ns
		$C_L = 50$ pF; $R_L = 500$ Ω ; $V_{CC} = 5$ V	1.9	ns
t_{PHZ}/t_{PLZ}	turn-off time E to V_{OS}	$C_L = 50$ pF; $R_L = 500$ Ω ; $V_{CC} = 3$ V	3.4	ns
		$C_L = 50$ pF; $R_L = 500$ Ω ; $V_{CC} = 5$ V	2.5	ns
C_I	input capacitance	$V_{CC} = 3$ V	3.5	pF
C_{PD}	power dissipation capacitance	$V_{CC} = 3.3$ V; notes 1 and 2	12.5	pF
C_S	switch capacitance	OFF-state	8.0	pF
		ON-state	14.0	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + ((C_L + C_S) \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

C_S = switch capacitance.

2. The condition is $V_I = \text{GND to } V_{CC}$.

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FUNCTION TABLE

See note 1.

INPUT nE	SWITCH
L	OFF
H	ON

Note

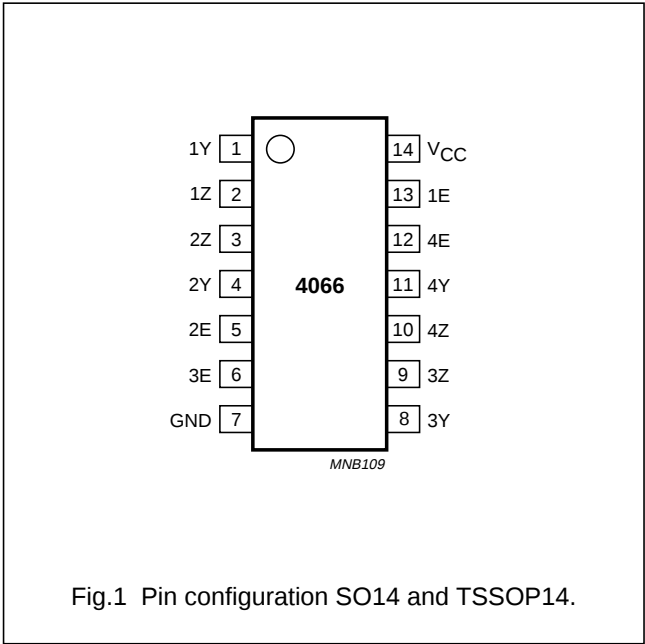
1. H = HIGH voltage level;
- L = LOW voltage level.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE
74LVC4066D	−40 to +125 °C	14	SO14	plastic	SOT108-2
74LVC4066PW	−40 to +125 °C	14	TSSOP14	plastic	SOT402-1
74LVC4066BQ	−40 to +125 °C	14	DHVQFN14	plastic	SOT762-1

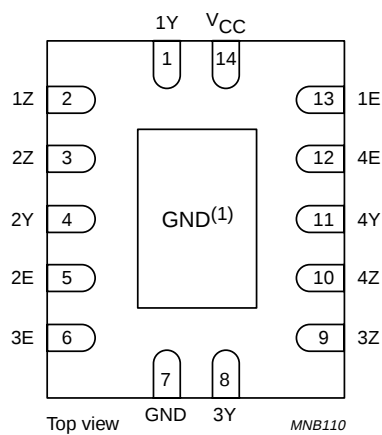
PINNING

PIN	SYMBOL	DESCRIPTION
1	1Y	independent input/output
2	1Z	independent output/input
3	2Z	independent output/input
4	2Y	independent input/output
5	2E	enable input (active HIGH)
6	3E	enable input (active HIGH)
7	GND	ground (0 V)
8	3Y	independent input/output
9	3Z	independent output/input
10	4Z	independent output/input
11	4Y	independent input/output
12	4E	enable input (active HIGH)
13	1E	enable input (active HIGH)
14	V _{CC}	supply voltage



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(1) The die substrate is attached to this pad using conductive die attach material. It can not be used as a supply pin or input.

Fig.2 Pin configuration DHVQFN14.

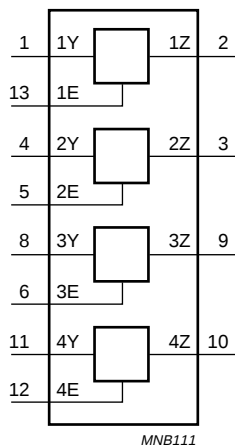


Fig.3 Logic symbol.

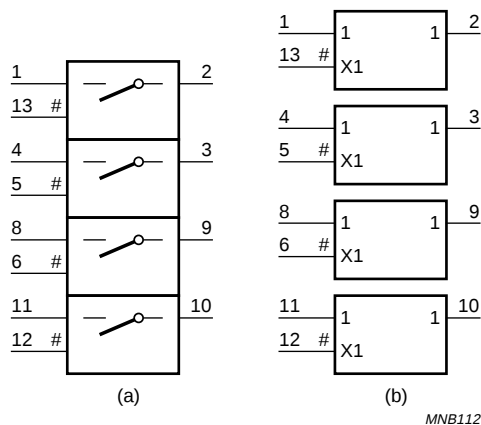


Fig.4 logic symbol (IEEE/IEC).

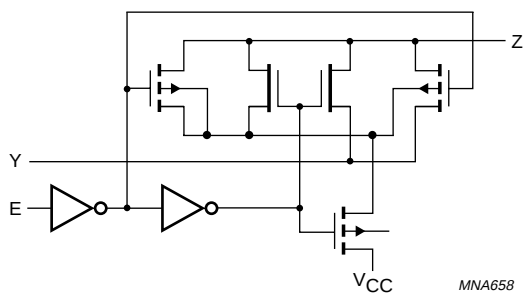


Fig.5 Logic diagram (one switch).

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		1.65	5.5	V
V_I	input voltage		0	5.5	V
V_S	switch voltage		0	V_{CC}	V
T_{amb}	operating ambient temperature		-40	+125	°C
t_r, t_f	input rise and fall times	$V_{CC} = 1.65$ to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7$ to 5.5 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V); see note 1.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		-0.5	+6.5	V
V_I	input voltage	note 2	-0.5	+6.5	V
I_{IK}	input diode current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V	–	-50	mA
I_{SK}	switch diode current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V	–	±50	mA
V_S	switch voltage	enable and disable mode	-0.5	+6.5	V
I_S	switch source or sink current	$-0.5 < V_S < V_{CC} + 0.5$ V	–	±50	mA
I_{CC}, I_{GND}	V_{CC} or GND current		–	±100	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	power dissipation	$T_{amb} = -40$ to $+125$ °C; note 3	–	500	mW

Notes

- To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminal Y. In this case there is no limit for the voltage drop across the switch, but the voltage at Y and Z may not exceed V_{CC} or GND.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- For SO14 packages: above 70 °C derate linearly with 8 mW/K.
For TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.
For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

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DC CHARACTERISTICS

At recommended operating conditions; voltage are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T _{amb} = −40 to +85 °C; note 1							
V _{IH}	HIGH-level input voltage		1.65 to 1.95	0.65V _{CC}	–	–	V
			2.3 to 2.7	1.7	–	–	V
			2.7 to 3.6	2.0	–	–	V
			4.5 to 5.5	0.7V _{CC}	–	–	V
V _{IL}	LOW-level input voltage		1.65 to 1.95	–	–	0.35V _{CC}	V
			2.3 to 2.7	–	–	0.7	V
			2.7 to 3.6	–	–	0.8	V
			4.5 to 5.5	–	–	0.30V _{CC}	V
I _{LI}	input leakage current (control pin)	V _I = 5.5 V or GND	5.5	–	±0.1	±5	μA
I _{S(OFF)}	analog switch OFF-state current	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; see Fig.7	5.5	–	±0.1	±5	μA
I _{S(ON)}	analog switch ON-state current	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; see Fig.8	5.5	–	±0.1	±5	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; V _S = GND or V _{CC} ; I _O = 0 A	5.5	–	0.1	10	μA
ΔI _{CC}	additional quiescent supply current per control pin	V _I = V _{CC} – 0.6 V; V _S = GND or V _{CC} ; I _O = 0 A	5.5	–	5	500	μA

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T _{amb} = −40 to +125 °C							
V _{IH}	HIGH-level input voltage		1.65 to 1.95	0.65V _{CC}	–	–	V
			2.3 to 2.7	1.7	–	–	V
			2.7 to 3.6	2.0	–	–	V
			4.5 to 5.5	0.7V _{CC}	–	–	V
V _{IL}	LOW-level input voltage		1.65 to 1.95	–	–	0.35V _{CC}	V
			2.3 to 2.7	–	–	0.7	V
			2.7 to 3.6	–	–	0.8	V
			4.5 to 5.5	–	–	0.30V _{CC}	V
I _{LI}	input leakage current (control pin)	V _I = 5.5 V or GND	5.5	–	–	±20	μA
I _{S(OFF)}	analog switch OFF-state current	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; see Fig.7	5.5	–	–	±20	μA
I _{S(ON)}	analog switch ON-state current	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; see Fig.8	5.5	–	–	±20	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; V _S = GND or V _{CC} ; I _O = 0 A	5.5	–	–	40	μA
ΔI _{CC}	additional quiescent supply current per control pin	V _I = V _{CC} – 0.6 V; V _S = GND or V _{CC} ; I _O = 0 A	5.5	–	–	5000	μA

Note

1. All typical values are measured at $T_{amb} = 25$ °C.

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Resistance R_{ON}

SYMBOL	PARAMETER	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT
		OTHER	I _S (mA)	V _{CC} (V)				
T _{amb} = −40 to +85 °C; note 1; see Fig.6								
R _{ON(peak)}	ON-resistance (peak)	V _S = GND to V _{CC} ; V _I = V _{IH}	4	1.65 to 1.95	–	35	100	Ω
			8	2.3 to 2.7	–	14	30	Ω
			12	2.7	–	11.5	25	Ω
			24	3.0 to 3.6	–	8.5	20	Ω
			32	4.5 to 5.5	–	6.5	15	Ω
R _{ON(rail)}	ON-resistance (rail)	V _S = GND; V _I = V _{IH}	4	1.65 to 1.95	–	10	30	Ω
			8	2.3 to 2.7	–	8.5	20	Ω
			12	2.7	–	7.5	18	Ω
			24	3.0 to 3.6	–	6.5	15	Ω
			32	4.5 to 5.5	–	6	10	Ω
		V _S = V _{CC} ; V _I = V _{IH}	4	1.65 to 1.95	–	12	30	Ω
			8	2.3 to 2.7	–	8.5	20	Ω
			12	2.7	–	7.5	18	Ω
			24	3.0 to 3.6	–	6.5	15	Ω
			32	4.5 to 5.5	–	6	10	Ω
R _{ON(flatness)}	ON-resistance (flatness)	V _S = GND to V _{CC} ; V _I = V _{IH} ; see Figs.10 to 13	4	1.8	–	100	–	Ω
			8	2.5	–	17	–	Ω
			12	2.7	–	10	–	Ω
			24	3.3	–	5	–	Ω
			32	5.0	–	3	–	Ω

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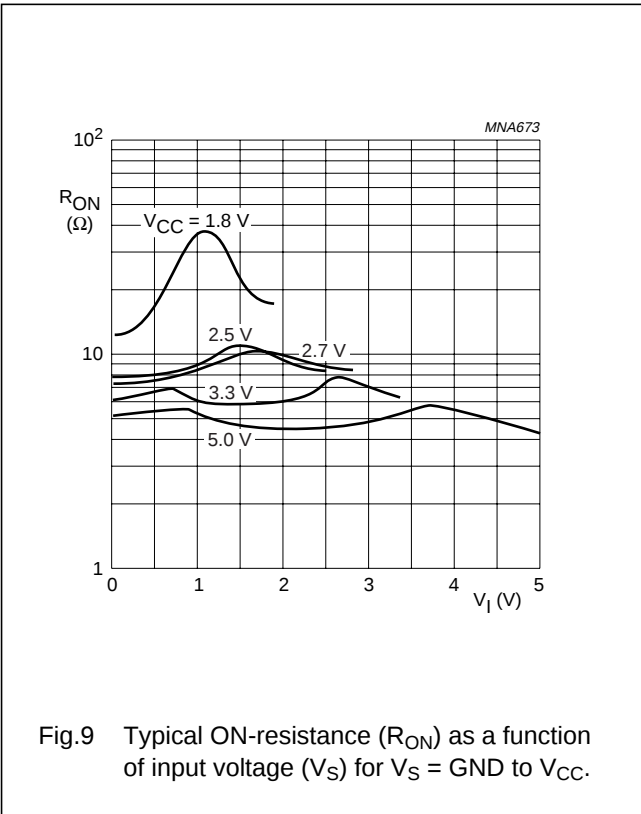
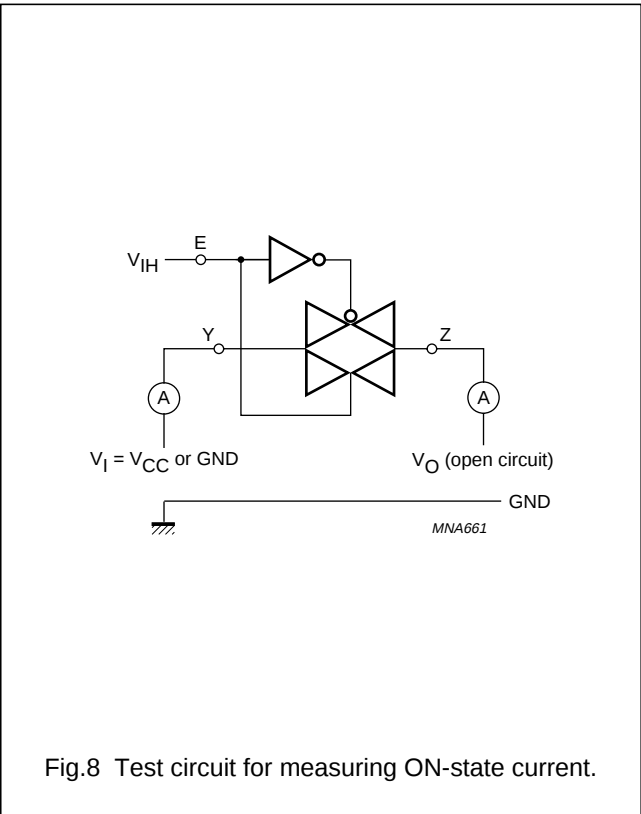
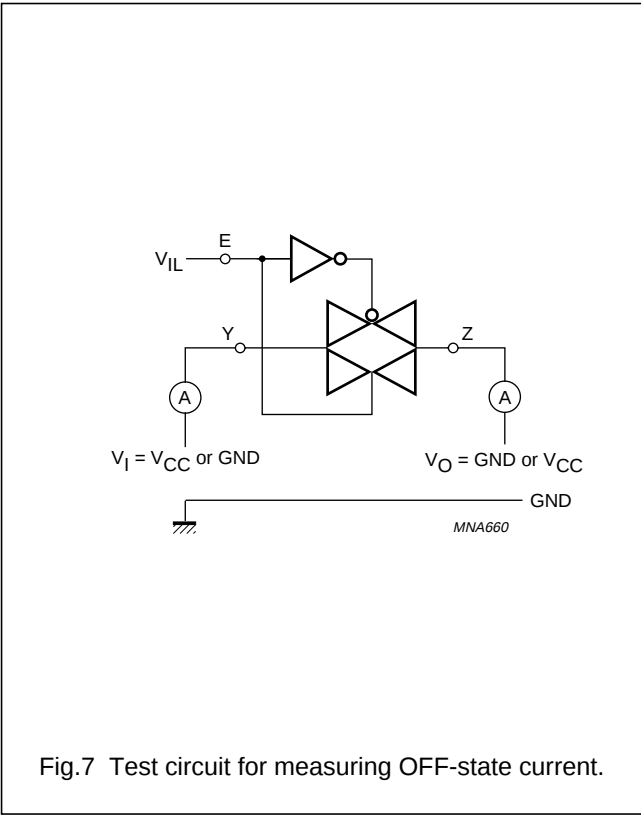
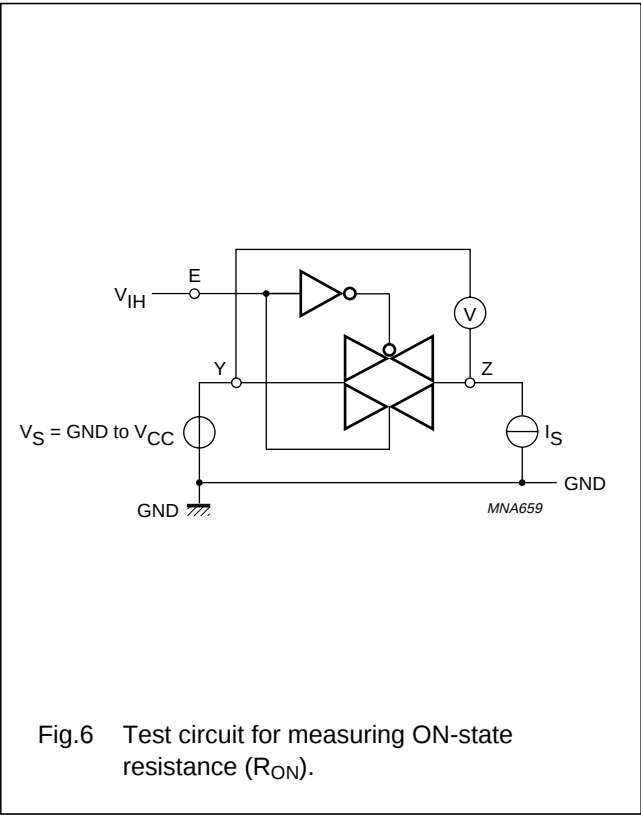
SYMBOL	PARAMETER	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT
		OTHER	I _S (mA)	V _{CC} (V)				
T _{amb} = −40 to +125 °C; see Fig.6								
R _{ON(peak)}	ON-resistance (peak)	V _S = GND to V _{CC} ; V _I = V _{IH}	4	1.65 to 1.95	–	–	150	Ω
			8	2.3 to 2.7	–	–	45	Ω
			12	2.7	–	–	38	Ω
			24	3.0 to 3.6	–	–	30	Ω
			32	4.5 to 5.5	–	–	23	Ω
R _{ON(rail)}	ON-resistance (rail)	V _S = GND; V _I = V _{IH}	4	1.65 to 1.95	–	–	45	Ω
			8	2.3 to 2.7	–	–	30	Ω
			12	2.7	–	–	27	Ω
			24	3.0 to 3.6	–	–	23	Ω
			32	4.5 to 5.5	–	–	15	Ω
		V _S = V _{CC} ; V _I = V _{IH}	4	1.65 to 1.95	–	–	45	Ω
			8	2.3 to 2.7	–	–	30	Ω
			12	2.7	–	–	27	Ω
			24	3.0 to 3.6	–	–	23	Ω
			32	4.5 to 5.5	–	–	15	Ω

Note

1. Typical value R_{on(flatness)} is measured at T_{amb} = –40 to +85 °C, all other typical values are measured at T_{amb} = 25 °C.

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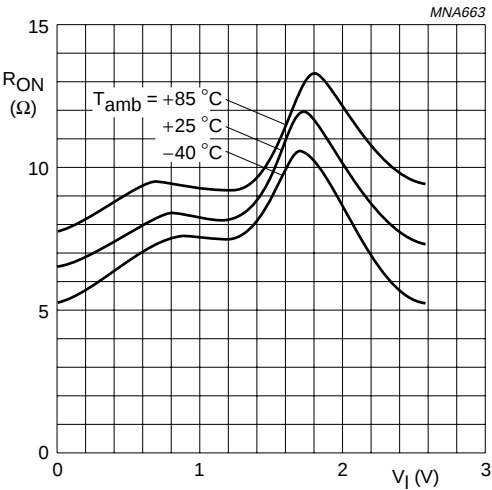


Fig.10 R_{ON} for $V_{CC} = 2.5\text{ V}$.

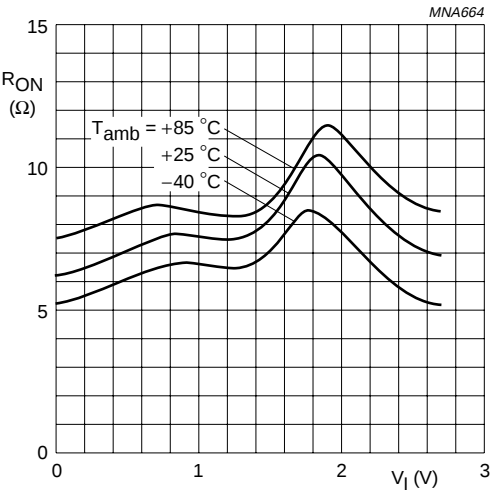


Fig.11 R_{ON} for $V_{CC} = 2.7\text{ V}$.

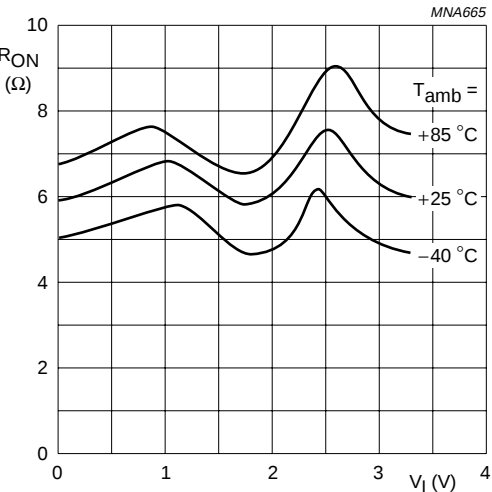


Fig.12 R_{ON} for $V_{CC} = 3.3\text{ V}$.

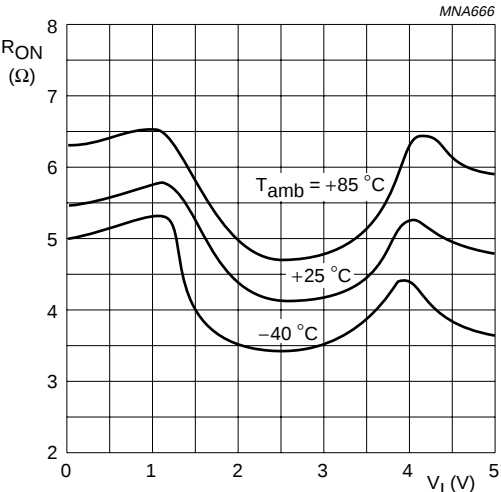


Fig.13 R_{ON} for $V_{CC} = 5.0\text{ V}$.

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AC CHARACTERISTICS

GND = 0 V.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T _{amb} = −40 to +85 °C; note 1							
t _{PHL} /t _{PLH}	propagation delay nY to nZ or nZ to nY	see Figs 14 and 16; note 2	1.65 to 1.95	–	0.8	2.0	ns
			2.3 to 2.7	–	0.4	1.2	ns
			2.7	–	0.4	1.0	ns
			3.0 to 3.6	–	0.3	0.8	ns
			4.5 to 5.5	–	0.2	0.6	ns
t _{PZH} /t _{PZL}	turn-ON time E to V _{OS}	see Figs 15 and 16	1.65 to 1.95	1.0	5.3	10	ns
			2.3 to 2.7	1.0	3.0	5.6	ns
			2.7	1.0	2.6	5.0	ns
			3.0 to 3.6	1.0	2.5	4.4	ns
			4.5 to 5.5	1.0	1.9	3.9	ns
t _{PHZ} /t _{PLZ}	turn-OFF time E to V _{OS}	see Figs 15 and 16	1.65 to 1.95	1.0	4.2	9.0	ns
			2.3 to 2.7	1.0	2.4	5.5	ns
			2.7	1.0	3.6	6.5	ns
			3.0 to 3.6	1.0	3.4	6.0	ns
			4.5 to 5.5	1.0	2.5	5.0	ns
T _{amb} = −40 to +125 °C							
t _{PHL} /t _{PLH}	propagation delay nY to nZ or nZ to nY	see Figs 14 and 16; note 2	1.65 to 1.95	–	–	3.0	ns
			2.3 to 2.7	–	–	2.0	ns
			2.7	–	–	1.5	ns
			3.0 to 3.6	–	–	1.5	ns
			4.5 to 5.5	–	–	1.0	ns
t _{PZH} /t _{PZL}	turn-ON time E to V _{OS}	see Figs 15 and 16	1.65 to 1.95	1.0	–	12.5	ns
			2.3 to 2.7	1.0	–	7.0	ns
			2.7	1.0	–	6.5	ns
			3.0 to 3.6	1.0	–	5.5	ns
			4.5 to 5.5	1.0	–	5.0	ns
t _{PHZ} /t _{PLZ}	turn-OFF time E to V _{OS}	see Figs 15 and 16	1.65 to 1.95	1.0	–	11.5	ns
			2.3 to 2.7	1.0	–	7.0	ns
			2.7	1.0	–	8.5	ns
			3.0 to 3.6	1.0	–	7.5	ns
			4.5 to 5.5	1.0	–	6.5	ns

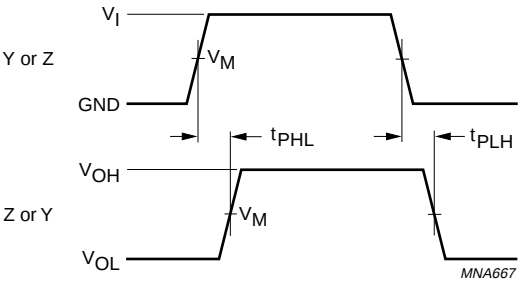
Notes

1. All typical values are measured at T_{amb} = 25 °C.
2. t_{PHL}/t_{PLH} propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).

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AC WAVEFORMS



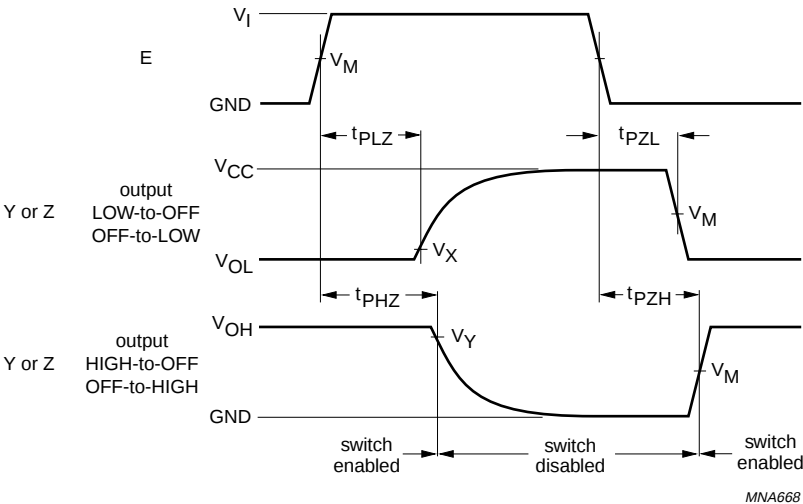
V_{CC}	V_M	INPUT	
		V_I	$t_r = t_f$
1.65 to 1.95 V	$0.5V_{CC}$	V_{CC}	$\leq 2.0\text{ ns}$
2.3 to 2.7 V	$0.5V_{CC}$	V_{CC}	$\leq 2.0\text{ ns}$
2.7 and 3.0 to 3.6 V	1.5 V	2.7 V	$\leq 2.5\text{ ns}$
4.5 to 5.5 V	$0.5V_{CC}$	V_{CC}	$\leq 2.5\text{ ns}$

V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig.14 The input (V_S) to output (V_O) propagation delays.

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V _{CC}	V _M	INPUT	
		V _I	t _r = t _f
1.65 to 1.95 V	0.5V _{CC}	V _{CC}	≤ 2.0 ns
2.3 to 2.7 V	0.5V _{CC}	V _{CC}	≤ 2.0 ns
2.7 and 3.0 to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns
4.5 to 5.5 V	0.5V _{CC}	V _{CC}	≤ 2.5 ns

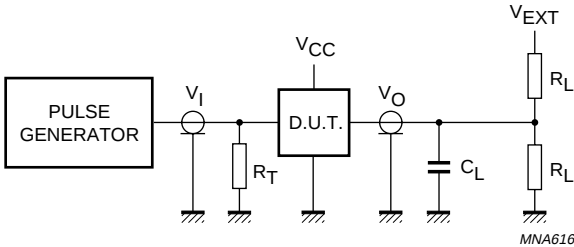
V_X = V_{OL} + 0.3 V at V_{CC} ≥ 2.7 V;
V_X = V_{OL} + 0.1 × V_{CC} at V_{CC} < 2.7 V;
V_Y = V_{OH} - 0.3 V at V_{CC} ≥ 2.7 V;
V_Y = V_{OH} - 0.1 × V_{CC} at V_{CC} < 2.7 V.

V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig.15 Turn-on and turn-off times.

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V _{CC}	V _I	C _L	R _L	V _{EXT}		
				t _{PLH} /t _{PHL}	t _{PZH} /t _{PHZ}	t _{PZL} /t _{PLZ}
1.65 to 1.95 V	V _{CC}	30 pF	1 kΩ	open	GND	2V _{CC}
2.3 to 2.7 V	V _{CC}	30 pF	500 Ω	open	GND	2V _{CC}
2.7 and 3.0 to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	6 V
4.5 to 5.5 V	V _{CC}	50 pF	500 Ω	open	GND	2V _{CC}

Definitions for test circuits:
R_L = Load resistor.
C_L = Load capacitance including jig and probe capacitance.
R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig.16 Load circuitry for switching times.

ADDITIONAL AC CHARACTERISTICS

Recommended conditions and typical values at T_{amb} = 25 °C.

SYMBOL	PARAMETER	TEST CONDITIONS	V _{CC} (V)	TYPICAL	UNIT
d _{sin}	sine-wave distortion	R _L = 10 kΩ; C _L = 50 pF; f _{in} = 1 kHz; see Fig.18	1.65	0.032	%
			2.3	0.008	%
			3	0.006	%
			4.5	0.005	%
		R _L = 10 kΩ; C _L = 50 pF; f _{in} = 10 kHz; see Fig.18	1.65	0.068	%
			2.3	0.009	%
			3	0.008	%
			4.5	0.006	%
f _{ON}	switch ON signal frequency response	R _L = 600 Ω; C _L = 50 pF; see Fig.17; note 1	1.65	170	MHz
			2.3	210	MHz
			3	212	MHz
			4.5	215	MHz
		R _L = 50 Ω; C _L = 5 pF; see Fig.17; note 1	1.65	> 500	MHz
			2.3	> 500	MHz
			3	> 500	MHz
			4.5	> 500	MHz

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SYMBOL	PARAMETER	TEST CONDITIONS	V _{CC} (V)	TYPICAL	UNIT
$\alpha_{\text{OFF(feedthru)}}$	switch OFF signal feed-through attenuation	$R_L = 600\ \Omega$; $C_L = 50\ \text{pF}$; $f_{\text{in}} = 1\ \text{MHz}$; see Fig.19; note 2	1.65	−46	dB
			2.3	−46	dB
			3	−46	dB
			4.5	−46	dB
		$R_L = 50\ \Omega$; $C_L = 5\ \text{pF}$; $f_{\text{in}} = 1\ \text{MHz}$; see Fig.19; note 2	1.65	−42	dB
			2.3	−42	dB
			3	−42	dB
			4.5	−42	dB
$\alpha_{\text{ct(E-Y/Z)}}$	crosstalk between control input to signal output	$R_L = 600\ \Omega$; $C_L = 50\ \text{pF}$; $f_{\text{in}} = 1\ \text{MHz}$; $t_r = t_f = 2\ \text{ns}$; see Fig.20	1.65	69	mV
			2.3	87	mV
			3	156	mV
			4.5	302	mV
$\alpha_{\text{ct(S)}}$	crosstalk between switches)	$R_L = 600\ \Omega$; $C_L = 50\ \text{pF}$; $f_{\text{in}} = 1\ \text{MHz}$; see Fig.21	1.65	−58	dB
			2.3	−58	dB
			3	−58	dB
			4.5	−58	dB
		$R_L = 50\ \Omega$; $C_L = 5\ \text{pF}$; $f_{\text{in}} = 1\ \text{MHz}$; see Fig.21	1.65	−58	dB
			2.3	−58	dB
			3	−58	dB
			4.5	−58	dB
C_{PD}	power dissipation capacitance	$f_{\text{in}} = 10\ \text{MHz}$	2.5	11.0	pF
			3.3	12.5	pF
			5.0	15.6	pF
Q	charge injection	$C_L = 0.1\ \text{nF}$; $V_{\text{gen}} = 0\ \text{V}$; $R_{\text{gen}} = 0\ \Omega$; $f = 1\ \text{MHz}$; $R_L = 1\ \text{M}\Omega$; see Fig.22; note 3	3.3	0.8	pC
			5.5	1.2	pC

Notes

1. Adjust f_{in} voltage to obtain 0 dBm level at output. Increase f_{in} frequency until dB meter reads −3 dB.
2. Adjust f_{in} voltage to obtain 0 dBm level at input.
3. Guaranteed by design.

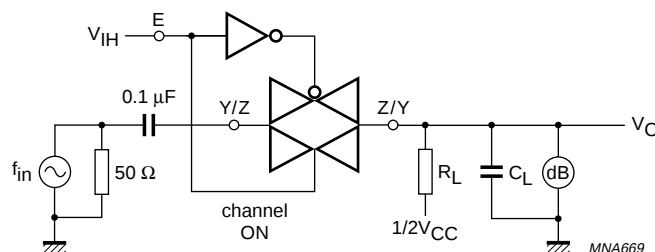
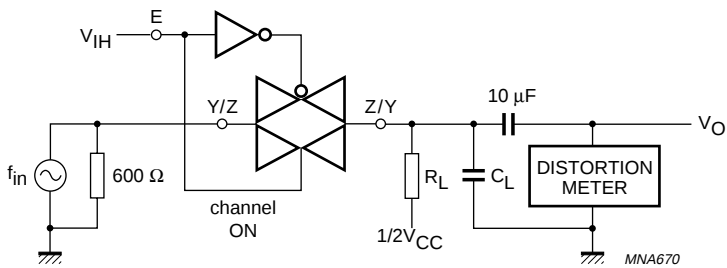


Fig.17 Test circuit for measuring the frequency response when switch is ON.

Quad bilateral switches

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V _{CC}	V _{IH}
1.65 V	1.4 V (p-p)
2.3 V	2 V (p-p)
3 V	2.5 V (p-p)
4. V	4 V (p-p)

Fig.18 Test circuit for measuring sine-wave distortion.

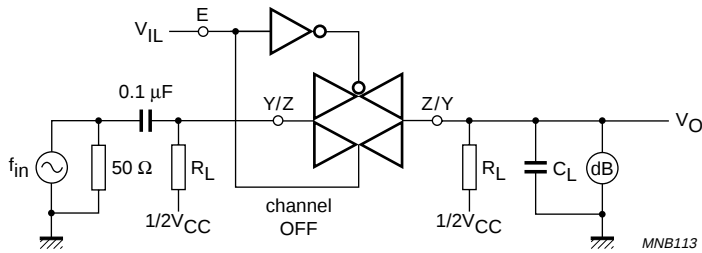


Fig.19 Test circuit for measuring feed-through when switch is OFF.

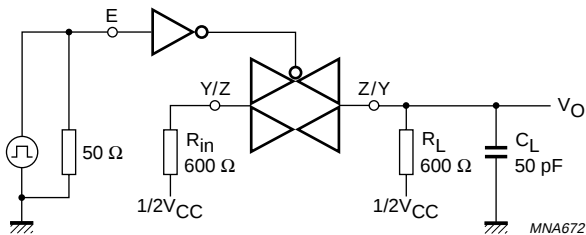


Fig.20 Crosstalk between control input to signal output.

Quad bilateral switches

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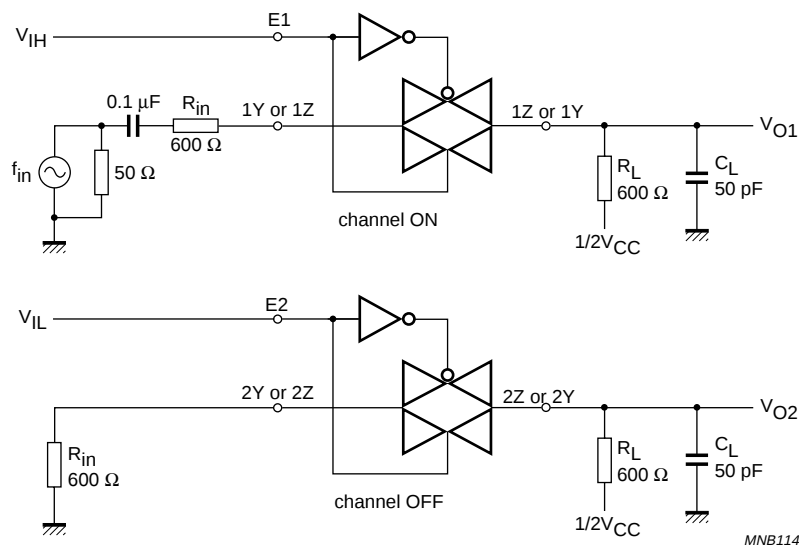
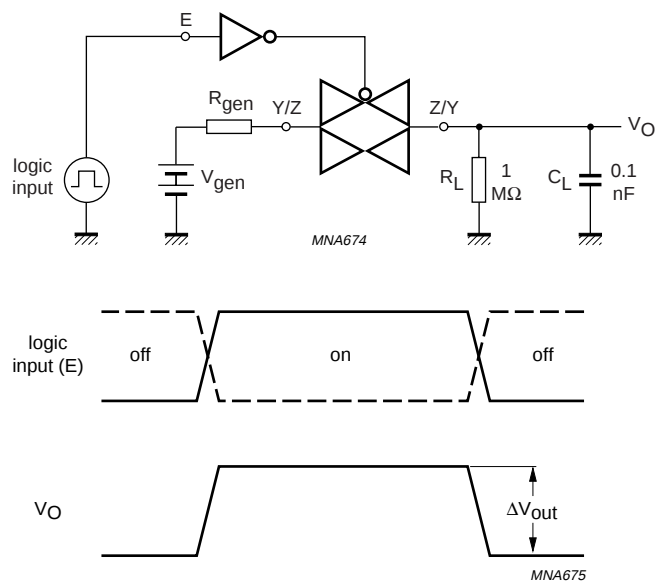


Fig.21 Crosstalk between switches.



$Q = \Delta V_{out} \times C_L$

Fig.22 Charge injection test.

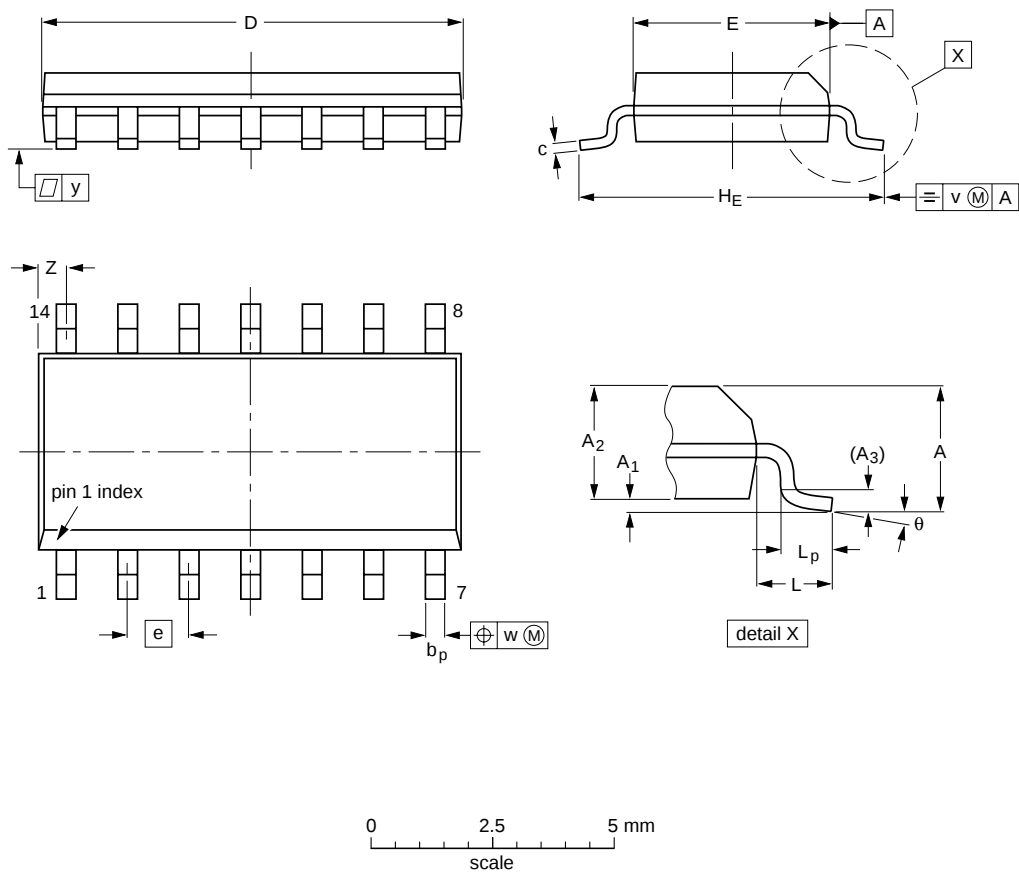
Quad bilateral switches

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PACKAGE OUTLINES

SO14: plastic small outline package; 14 leads; body width 3.9 mm; body thickness 1.47 mm

SOT108-2

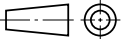


DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	v	w	y	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.55 1.40	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.061 0.055	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

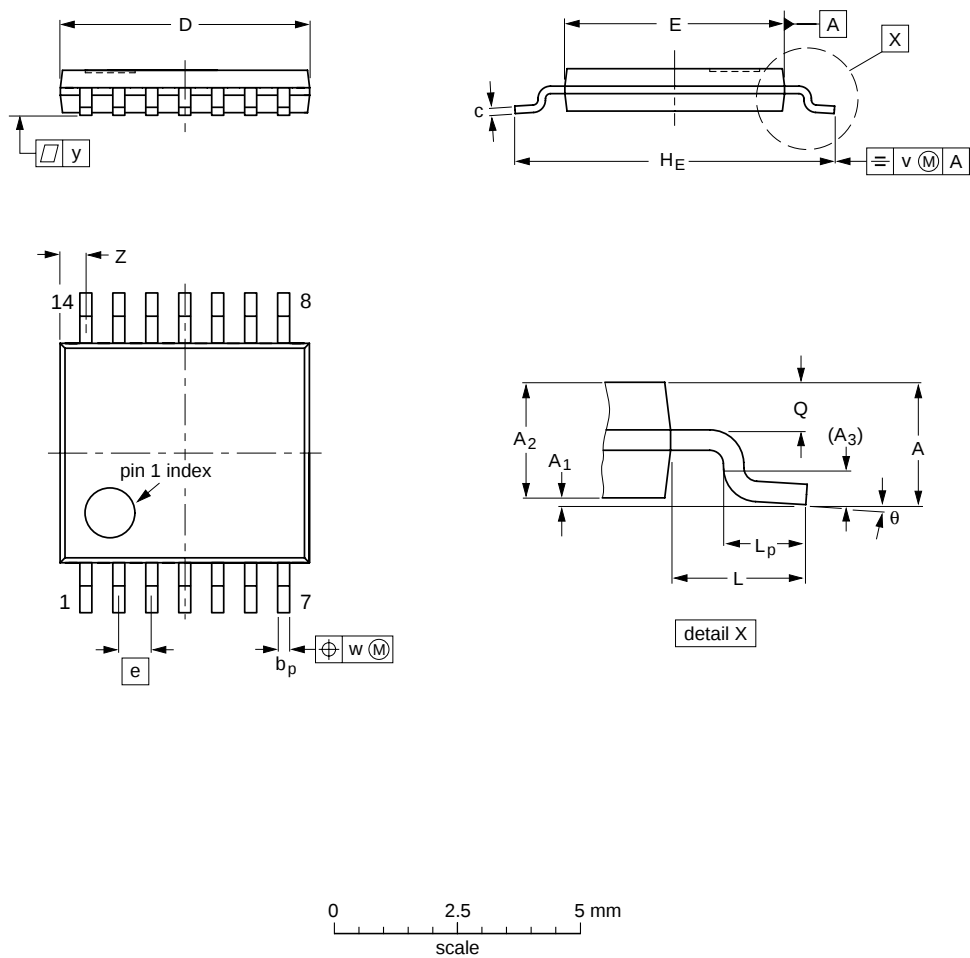
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT108-2		MS-012				01-05-29 03-02-19

Quad bilateral switches

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

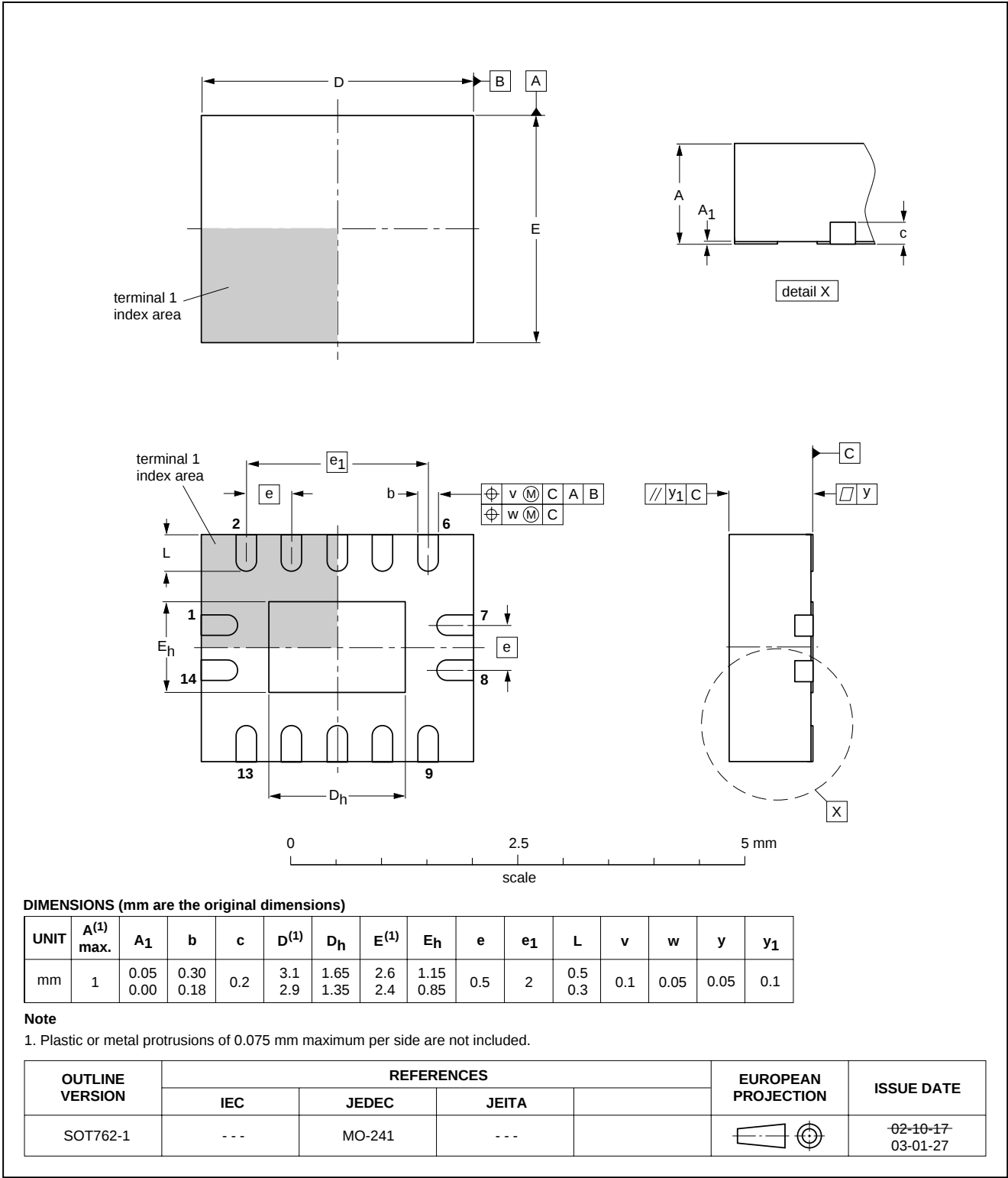
- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT402-1		MO-153				99-12-27- 03-02-18

Quad bilateral switches

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;
14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1



Quad bilateral switches

74LVC4066

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

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2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.
3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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